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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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Peter T. Larsen

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EXAMINER

PATEL, HETUL B

ART UNIT

PAPER NUMBER

2186

DATE MAILED: 02/06/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

**Office Action Summary**

Application No.

10/602,320

Applicant(s)

LARSEN, PETER T.

Examiner

Hetul Patel

Art Unit

2186

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

**Period for Reply**

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 03 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

- 1) ☒ Responsive to communication(s) filed on 23 January 2006.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

- 4) ☒ Claim(s) 1-3,5-10,13-16,18-24 and 26-28 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1-3,5-10,13-16,18-24 and 26-28 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on \_\_\_\_\_ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

**Priority under 35 U.S.C. § 119**

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some \* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
  2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

\* See the attached detailed Office action for a list of the certified copies not received.

**Attachment(s)**

- |  |   |
|--|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892)   | 4) <input type="checkbox"/> Interview Summary (PTO-413)<br>Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)                                   | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152)             |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)<br>Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____  |

## DETAILED ACTION

1. This Office Action is in response to the communication filed on January 23, 2006. Claims 4, 11, 12, 17 and 25 are cancelled and claims 1-2, 5-7, 9-10, 13-14, 18-20, 22-23, 26 and 28 are amended. Claims 1-3, 5-10, 13-16, 18-24 and 26-28 are currently pending in this application.
2. Applicant's arguments filed on January 23, 2006 have been fully considered but they are not deemed to be persuasive.

### ***Claim Rejections - 35 USC § 102***

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

3. Claims 1, 3, 5-9, 19, 21-24 and 26-28 are rejected under 35 U.S.C. 102(b) as being anticipated by Terauchi (USPN: 5,862,147).

As per claim 1, Terauchi teaches a method of programming a FLASH memory device (i.e. the flash memory 21 in Figs. 1-2) comprising: issuing a blank check

command (i.e. blank check operation) to a command register within the FLASH memory device (i.e. the flash memory 21 in Figs. 1-2), wherein the blank check command specifies a specified block to blank check (i.e. repeating the blank check steps for more than one flash memories (blocks) on the wafer (memory device) (e.g. see Fig. 1)); checking a signal level (i.e. the bit(s) where the result is written in the second memory area 23 in Fig. 2) on a conductor coupled to the FLASH memory device to verify that the specified block is blank; and programming memory locations within the specified block (i.e. the portion) of the FLASH memory device (i.e. writing/programming only those addresses that verified as blank, see S41-S44 in Fig. 4) (e.g. see Col. 4, lines 36-58; Col. 5, lines 18-21 and Figs. 1-2 and 4).

As per claim 7, Terauchi teaches a method of blank checking and programming a FLASH memory device (i.e. the flash memory 21 in Figs. 1-2) comprising: receiving a blank check command (i.e. blank check operation) from a device (i.e. the microcomputer 24 in Fig. 2) external to the FLASH memory device, wherein the blank check command specifies a specified block to blank check (i.e. repeating the blank check steps for more than one flash memories (blocks) on the wafer (memory device) (e.g. see Fig. 1)); in response to the blank check command received from a device external to the FLASH memory device, reading a plurality of memory locations in the specified block of the memory device; asserting a signal (i.e. the bit(s) where the result is written in the second memory area 23 in Fig. 2) on a conductor coupled to the device external to the FLASH memory device to signify that the specified block is blank; and

receiving data to be programmed in the at least one block (e.g. see Col. 4, lines 36-58; Col. 5, lines 18-21 and Figs. 1-2 and 4).

As per claim 19, see arguments with respect to the rejection of claim 7. Claim 19 is also rejected based on the same rationale as the rejection of the claim 7.

As per claim 3, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that issuing a blank check command comprises: issuing a blank check setup command (i.e. step S42 in Fig. 4); and issuing a blank check confirm command (i.e. step S43 in Fig. 4) (e.g. see Col. 2, lines 36+ and Fig. 4).

As per claims 8, 21 and 27, see arguments with respect to the rejection of claim 3. Claims 8, 21 and 27 are also rejected based on the same rationale as the rejection of the claim 3.

As per claims 5 and 6, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that the method further comprising repeating the issuing, checking and programming steps for more than one block in the memory device, i.e. repeating these steps for more than one and each flash memories (blocks) on the wafer (memory device) (e.g. see Fig. 1).

As per claims 22 and 28, see arguments with respect to the rejection of claims 5-6. Claims 22 and 28 are also rejected based on the same rationale as the rejection of the claims 5-6.

As per claim 9, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that reading a plurality of memory locations comprises

reading each memory location in the at least one block (i.e. the block between the 'RESET' address and 'FULL' address specified) (e.g. see Col.2, lines 36+ and Fig. 5).

As per claim 23, Terauchi teaches an electronic system comprising a direct conversion receiver (i.e. the pad 31f in Fig. 3 that receives the test control signals); a processor (i.e. 24 in Fig. 2) coupled to the direct conversion receiver; and a memory device (i.e. 21 in Fig. 2) coupled to the processor, the memory device including a FLASH memory core (i.e. 22 in Fig. 2) and a control block (the combination of 24 and 25 in Fig. 2) adapted to blank check a specified block of the FLASH memory core; and an external interface (i.e. 61 in Fig. 6) to allow communication between the control block and the processor, the external interface including a command register (i.e. the R1 and R2 in Fig. 6) to receive a blank check command that specifies the specified block (i.e. by plugging different values for R1 and R2 in Fig. 6), wherein the control block is capable of blank checking the specified block of the FLASH memory core during a programming operation by the processor, and wherein the control block is further capable of asserting a signal on a conductor external to the memory device to signify that the specified block is blank (e.g. see Col. 4, lines 36-58; Col. 5, lines 18-21; Col. 6, lines 13+ and Figs. 2-3 and 6).

As per claim 24, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that the control block comprises a microcontroller (i.e. the microcomputer 24 in Fig. 2).

As per claim 26, Terauchi teaches an electronic system comprising a direct conversion receiver (i.e. the pad 31f in Fig. 3 that receives the test control signals); a

FLASH memory device (i.e. 21 in Fig. 2); a processor (i.e. 24 in Fig. 2) coupled to the direct conversion receiver and the FLASH memory device wherein the blank check command specifies a specified block to blank check (i.e. repeating the blank check steps for more than one flash memories (blocks) on the wafer (memory device) (e.g. see Fig. 1)); checking a signal level (i.e. the bit(s) where the result is written in the second memory area 23 in Fig. 2) on a conductor coupled to the FLASH memory device to verify that the specified block is blank; and programming memory locations within the specified block (i.e. the portion) of the FLASH memory device (i.e. writing/programming only those addresses that verified as blank, see S41-S44 in Fig. 4) (e.g. see Col. 4, lines 36-58; Col. 5, lines 18-21 and Figs. 1-2 and 4).

4. Claims 13, 15-16 and 18 are rejected under 35 U.S.C. 102(e) as being anticipated by Shokouhi (USPN: 6,651,199).

As per claim 13, Shokouhi teaches a memory device (i.e. 100 in Figs. 2-3A) comprising: a FLASH memory core (i.e. the memory circuit 120 in Figs. 2-3A); a control block (i.e. 110 in Fig. 2) adapted to blank check at least a portion of the FLASH memory core; and an external interface (i.e. 110 in Fig. 2) to allow communication between the control block and a device (i.e. the JTAG-based operating system) external to the memory device, the external interface including a command register (i.e. the R1 and R2 in Fig. 6) to receive a blank check command that specifies the specified block (i.e. by plugging different values for R1 and R2 in Fig. 6), wherein the control block is capable of blank checking the specified block of the FLASH memory core during a programming

operation when the memory device is in use in a system, and wherein the control block is further capable of asserting a signal on a conductor external to the memory device to signify that the specified block is blank (e.g. see Col. 4, lines 36-58; Col. 5, lines 18-21; Col. 6, lines 13+ and Figs. 2-3 and 6).

As per claim 18, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that the external interface comprises a status register (i.e. 320 in Fig. 4 to hold the current state) (e.g. see Fig. 4).

As per claim 15, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that the control block comprises a state machine (i.e. 320 in Fig. 4) (e.g. see Figs. 4 and 6).

As per claim 16, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that the control block comprises a microcontroller (i.e. 220 in Fig. 3A).

### ***Claim Rejections - 35 USC § 103***

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

5. Claims 2, 10, 14 and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over Terauchi in view of Salzman (USPN: 5,438,536).

As per claim 2, Terauchi teaches the claimed invention as described above. However, Terauchi does not teach about checking a busy bit. Salzman, on the other hand, teaches that the ready line of the flash memory, which indicates whether the particular flash memory is ready or not, i.e. whether it is busy or not is checked before providing an interrupt signal (e.g. see the abstract and claim 1). Accordingly, it would have been obvious to one of ordinary skill in the art at the time of the current invention was made to implement step of checking the busy bit in the memory device as taught by Salzman in Terauchi's method. In doing so, the busy bit can be checked before checking the signal level on the conductor to make sure the memory device is not busy; and if the busy bit is indicating busy, then the signal level on the conductor will not be valid at that time, i.e. it reduces the need for polling signal level on the conductor.

As per claim 20, see arguments with respect to the rejection of claim 2. Claim 20 is also rejected based on the same rationale as the rejection of the claim 2.

As per claim 10, Terauchi teaches the claimed invention as described above. However, Terauchi does not teach about setting a busy bit. Salzman, on the other hand, teaches that the ready line of the flash memory, which indicates whether the particular flash memory is ready or not, i.e. whether it is busy or not is set before providing an interrupt signal (e.g. see the abstract and claim 1). Accordingly, it would have been obvious to one of ordinary skill in the art at the time of the current invention was made to implement step of checking/setting the busy bit in the memory device as taught by Salzman in Terauchi's method. In doing so, the busy bit can be checked before checking the signal level on the conductor to make sure the memory device is

not busy; and if the busy bit is indicating busy, then the signal level on the conductor will not be valid at that time, i.e. it reduces the need for polling signal level on the conductor. Salzman also teaches the further limitation of clearing the busy bit (i.e. indicating the ready state) after asserting (i.e. after completing the write or erase operation) the signal on the conductor (e.g. see claim 1).

As per claim 14, Terauchi teaches the claimed invention as described above and furthermore, Terauchi teaches that the external interface comprises a status register (i.e. 320 in Fig. 4 to hold the current state) (e.g. see Fig. 4). However, Terauchi does not teach that the status register adapted to signify that the memory is busy. Salzman, on the other hand, teaches that the ready line of the flash memory, which indicates whether the particular flash memory is ready or not, i.e. whether it is busy or not is checked before providing an interrupt signal (e.g. see the abstract and claim 1). Accordingly, it would have been obvious to one of ordinary skill in the art at the time of the current invention was made to modify the status register of Terauchi so it can signify that the memory is busy as taught by Salzman. In doing so, the busy bit can be checked before checking the signal level on the conductor to make sure the memory device is not busy; and if the busy bit is indicating busy, then the signal level on the conductor will not be valid at that time, i.e. it reduces the need for polling signal level on the conductor.

***Remarks***

6. As to the remark, Applicant asserted that none of the prior arts of record teaches the features of:

- (a) specifying a block to be checked.
- (b) asserting a signal level on a conductor to signify whether the specified block is blank.

Examiner respectfully traverses Applicant's remark for the following reasons:

With respect to (a), Terauchi does teach that the blank check command specifies a specified block to blank check, i.e. the blank check steps are repeated for more than one flash memories (blocks) on the wafer (memory device) specifying one block a time (e.g. see Fig. 1).

With respect to (b), Terauchi also teaches about checking a signal level (i.e. the bit(s) where the result is written in the second memory area 23 in Fig. 2) on a conductor coupled to the FLASH memory device to verify that the specified block is blank; and programming memory locations within the specified block (i.e. the portion) of the FLASH memory device (i.e. writing/programming only those addresses that verified as blank, see S41-S44 in Fig. 4) (e.g. see Col. 4, lines 36-58; Col. 5, lines 18-21 and Figs. 1-2 and 4).

**Conclusion**


7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Hetul Patel whose telephone number is 571-272-4184. The examiner can normally be reached on M-F 8-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matt Kim can be reached on 571-272-4182. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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**MATTHEW D. ANDERSON**  
**PRIMARY EXAMINER**